

## **Product Description**

Teccor's Alternistor QUADRAC is a triac that includes a diac trigger mounted inside the same package. This device, developed by Teccor, saves the user the expense of buying a discrete diac and assembling in conjunction with a gated triac. Also, the Alternistor triac eliminates the need for a snubber network.

The Alternistor QUADRAC is a bidirectional AC switch and is gate controlled for either polarity of main terminal voltage. Its primary purpose is for AC switching and phase control applications such as speed controls, temperature modulation controls, and lighting controls where noise immunity is required.

Alternistor QUADRAC current capacities range from 6 to 15 Amperes with voltage ranges from 400-600 Volts and are available in the TO-220AB package as shown above.

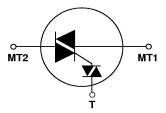
The Thermotab package is electrically isolated to 2,500 V (RMS) from the leads to mounting surface. A 4,000 V (RMS) rating is available on special order. This means that no external isolation is required, thus eliminating the need for separate insulators and insulator-mounting steps saving dollars over "hot tab" devices.

All Teccor dice have glass-passivated junctions to ensure long term reliability and parametric stability. Variations of devices in this data sheet are available for custom design applications. Please consult the factory for more information.

### **Features**

- Glass-passivated junctions
- Electrically-isolated package
- Internal trigger diac
- High surge capability up to 200 Amps
- · High voltage capability 400 up to 600 Volts

# Alternistor Quadrac<sup>®</sup> Internally Triggered Triacs (6 - 15 Amps)





# **Electrical Specifications**

I <sub>T(RMS)</sub>	Part No.	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				Trigger Diac Specifications (T–MT1)						
	Isolated	V <sub>DRM</sub>		I <sub>DRM</sub>		V <sub>TM</sub>	ΔV <sub>BO</sub>	V <sub>BO</sub>		[ΔV±]	I <sub>BO</sub>	C <sub>T</sub>
RMS On-State Current Conduction Angle of 360° (5)		Repetitive Peak Blocking Voltage (1)	Peak Off-State Current Gate Open VDRM = Max Rated Value (1) (10) mAmps			Peak On-State Voltage at Max Rated RMS Current T <sub>C</sub> = 25°C (1) (3)	Breakover Voltage Symmetry (7)	Breakover Voltage (Forward & Reverse) (6)		Dynamic Breakback Voltage (Forward & Reverse) (6)	Peak Break- over Current	Trigger Firing Capaci- tance (11)
	MT1 T T MT2 THERMOTAB TO-220AB	Volts	T <sub>C</sub> = 25°C	T <sub>C</sub> = 100°C	T <sub>C</sub> = 125°C	Volts	Volts		olts	Volts	μ <b>A</b> mps	μFarads
		MIN		MAX		MAX	MAX	MIN	мах	MIN	MAX	мах
	Q4006LTH	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
6.0 Amps	Q5006LTH	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
olo milipo	Q6006LTH	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q4008LTH	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
8.0 Amps	Q5008LTH	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
0.0 Amps	Q6008LTH	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q4010LTH	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
10.0 Amps	Q5010LTH	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6010LTH	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q4015LTH	400	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
15.0 Amps	Q5015LTH	500	.05	0.5	2.0	1.6	3	33	43	5	25	0.1
	Q6015LTH	600	.05	0.5	2.0	1.6	3	33	43	5	25	0.1

## **General Notes**

- All measurements are made at 60Hz with resistive load at an ambient temperature of +25°C unless otherwise specified.
- Operating temperature range (T<sub>J</sub>) is -40°C to +125°C.
- Storage temperature range (T<sub>S</sub>) is -40°C to +125°C.
- Lead solder temperature is a maximum of +230°C for 10 seconds maximum; ≥ 1/16" (1.59mm) from case.
- The case temperature (T<sub>C</sub>) is measured as shown on dimensional outline drawings.

## **Electrical Specification Notes**

- (1) For either polarity of MT2 with reference to MT1.
- (2) See Figure 1.1 for  $I_H$  vs.  $T_C$ .
- (3) See Figures 1.4 and 1.5 for i<sub>T</sub> vs. v<sub>T</sub>.
- (4) See Figure 1.9 for surge ratings with specific durations.
- (5) See Figures 1.6 and 1.7 for current rating at specific operating temperature.
- (6) See Figures 1.2 and 1.3 for test circuit.
- (7)  $\Delta V_{BO} = [+ V_{BO}] [- V_{BO}]$
- (8) See Figure 1.7 for maximum allowable case temperature at maximum rated current.
- (9) Trigger firing capacitance =  $0.1\mu$ F with  $0.1\mu$ s rise time.
- (10)  $T_C = T_J$  for test conditions in off-state.
- (11) Maximum required value to ensure sufficient gate current.

THERMAL RESISTANCE (STEADY STATE) $R_{\theta JC} [R_{\theta JA(TYP)}] \circ C/WATT$						
TYPE	ISOLATED TO-220AB					
6.0 Amps	3.3 [50]					
8.0 Amps	2.8					
10.0 Amps	2.6					
15.0 Amps	2.1					

### **Electrical Isolation**

 All Teccor isolated TO-220AB packages will withstand a minimum high potential test of 2500VAC (RMS) from leads to mounting tab over the operating temperature range of the device. See isolation table for standard and optional isolation ratings.

ELECTRICAL ISOLATION FROM LEADS TO MOUNTING TAB **						
VAC(RMS)	TYPE					
2500	Standard					
4000	Optional*					

<sup>\*</sup> For 4000 V isolation use "V" suffix.

<sup>\*\*</sup> U.L. Recognized File #E71639

I <sub>H</sub>	I <sub>T</sub>	SM	dv/dt(c)	dv/dt		t <sub>gt</sub>	l <sup>2</sup> t	I <sub>GTM</sub>	di/dt	
Holding Current Gate Open (1) (2)	Peak One Cycle Surge (4) (8)		Critical Rate-of-Rise of Commutation Voltage at Rated V <sub>DRM</sub> and I <sub>T(RMS)</sub> Commutating di/dt = 0.54 Rated I <sub>T(RMS)</sub> /ms	Critical Rate-of- Rise of Off-State Voltage at Rated V <sub>DRM</sub> Gate Open (1)		Gate Controlled Turn-On Time (6) (9)	RMS Surge (Non-Repetitive) On-State Current for period of 8.3ms for Fusing	Peak Gate Trigger Current (10µs Max)	Maximum Rate-of-Change of On-State Current (9)	
			Gate Unenergized (1) (5) (8)	T <sub>C</sub> = 100°C	T <sub>C</sub> = 125°C		. 20			
mAmps		nps				μSec	Amps <sup>2</sup> Sec	Amps	Amps/μSec	
	60Hz	OHz 50Hz MIN MIN TYP		TYP						
50	80	65	25	575	450	3	26.5	1.5	70	
50	80	65	25	500	400	3	26.5	1.5	70	
50	80	65	25	425	350	3	26.5	1.5	70	
50	100	83	25	575	450	3	41	1.5	70	
50	100	83	25	500	400	3	41	1.5	70	
50	100	83	25	425	350	3	41	1.5	70	
60	120	100	30	925	700	3	60	1.5	70	
60	120	100	30	850	650	3	60	1.5	70	
60	120	100	30	775	600	3	60	1.5	70	
70	200	167	30	925	700	3	166	1.5	100	
70	200	167	30	850	650	3	166	1.5	100	
70	200	167	30	775	600	3	166	1.5	100	

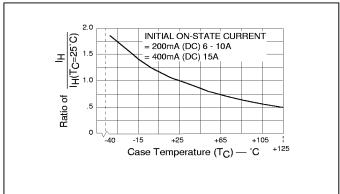


Figure 1.1 Normalized DC Holding Current vs. Case Temperature

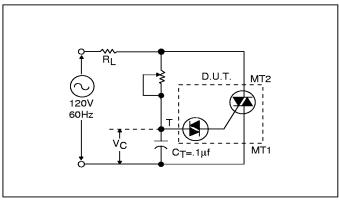


Figure 1.2 Test Circuit

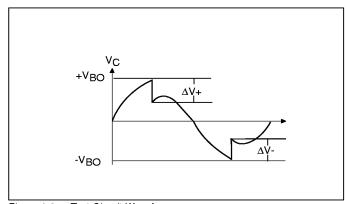


Figure 1.3 Test Circuit Waveforms

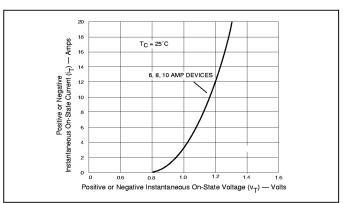


Figure 1.4 On-State Current vs. On-State Voltage (Typical) (6-10 Amp)

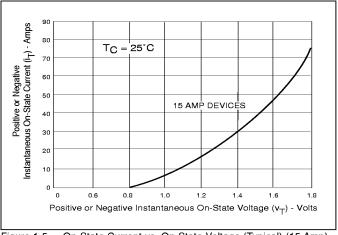


Figure 1.5 On-State Current vs. On-State Voltage (Typical) (15 Amp)

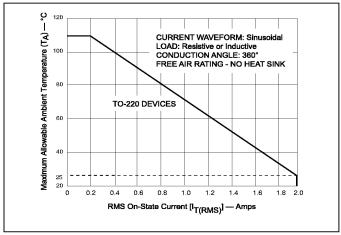


Figure 1.6 Maximum Allowable Ambient Temperature vs.
On-State Current

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Please contact the factory for further information.

Data Sheet: AltQuadrac-1098

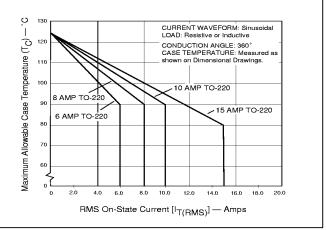


Figure 1.7 Maximum Allowable Case Temperature vs. On-State Current (6-15 Amp)

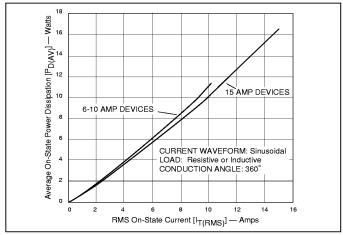


Figure 1.8 Power Dissipation (Typical) vs.
On-State Current (6-10 and 15 Amp)

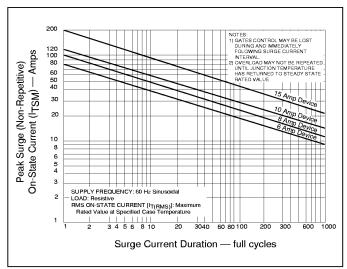


Figure 1.9 Peak Surge Current vs. Surge Current Duration



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